

CMOS LOGIC IC ELM7S00B 2-input NAND gate

<https://www.elm-tech.com>

■General description

ELM7S00B is CMOS 2-input NAND gate IC. It realizes high speed operation similar to LS-TTL with lower power consumption because of CMOS features. The inner circuit structure of 3-stage logic gate obtains wider noise immunity and constant output.

■Features

- Same electrical characteristic as 74HC series (output current is around 1/2 of 74HC series)
- Low consumption current : $I_{dd}=1.0\mu A$ (Max.)(Top=25°C)
- Wide power voltage range : 2.0V to 6.0V
- High speed : $T_{pd}=5ns$ (Typ.)(Vdd=5.0V)
- Symmetrical output impedance : $|I_{oh}|=I_{ol}=2mA$ (Min.)(Vdd=4.5V)
- Small package : SOT-25

■Application

- Cell phones
- Digital cameras
- Portable electrical appliances like PDA, etc.
- Computers and peripherals
- Digital electrical appliances like LCD TV sets, DVD recorders/players, STB, etc.
- Modification inside print board, adjustment of timing, solution to noise

■Selection guide

ELM7S00BEL

Symbol	Function	00: 2-input NAND gate
a	Product version	B
c	Taping direction	EL: Refer to PKG file

ELM7S 0 0 B EL
↑ ↑ ↑
a b c

■Maximum absolute ratings

Parameter	Symbol	Limit	Unit
Power supply voltage	Vdd	-0.5 to +7.0	V
Input voltage	Vin	-0.5 to Vdd+0.5	V
Output voltage	Vout	-0.5 to Vdd+0.5	V
Input protection diode current	Iik	± 20	mA
Output parasitic diode current	Iok	± 20	mA
Output current	Iout	± 25	mA
VDD/GND current	Idd, Ignd	± 25	mA
Power dissipation	Pd	200	mW
Storage temperature	Tstg	-65 to +150	°C

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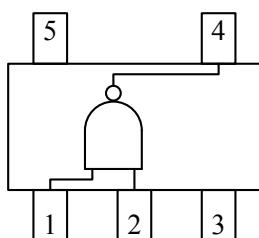
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■Suggested operating condition

Parameter	Symbol	Limit		Unit
Power voltage	Vdd	2.0 to 6.0		V
Input voltage	Vin	0 to Vdd		V
Output voltage	Vout	0 to Vdd		V
Operating temperature	Top	-40 to +85		°C
High-input down-time	tr, tf	Vdd=2.0V	0 to 1000	ns
		Vdd=4.5V	0 to 500	
		Vdd=6.0V	0 to 400	

■Pin configuration

SOT-25(TOP VIEW)



Pin No.	Pin name
1	INB
2	INA
3	GND
4	OUTX
5	VDD

Input	Output
INA	INB
Low	Low
Low	High
High	Low
High	High

■AC electrical characteristics

CL=15pF, tr=tf=6ns, Vdd=5V

Parameter	Sym.	Vdd	Top=25°C			Unit	Condition
			Min.	Typ.	Max.		
Output transition time	tTLH		4	10		ns	Refer to test circuit
	tTHL		3	10			
Propagation delay-time	tPLH		5	15		ns	Refer to test circuit
	tPHL		5	15			

CL=50pF, tr=tf=6ns

Parameter	Sym.	Vdd	Top=25°C			Top=-40 to +85°C		Unit	Condition	
			Min.	Typ.	Max.	Min.	Max.			
Output transition time	tTLH	2.0		18	125		155	ns	Refer to test circuit	
		4.5		7	25		31			
		6.0		6	21		26			
	tTHL	2.0		14	125		155	ns		
		4.5		6	25		31			
		6.0		6	21		26			
Propagation delay-time	tPLH	2.0		16	100		125	ns	Refer to test circuit	
		4.5		8	20		25			
		6.0		7	17		21			
	tPHL	2.0		16	100		125	ns		
		4.5		6	20		25			
		6.0		5	17		21			
Input capacity	Cin			5	10		10	pF		
Equivalent inner capacity	Cpd			10				pF		

* Cpd is IC's inner equivalent capacity which is calculated from non-loaded operating current consumption referred to test circuit. Averaged operating current consumption at non load is calculated as following formula: $Idd(\text{opr}) = Cpd \cdot Vdd \cdot f_{in} + Idd$

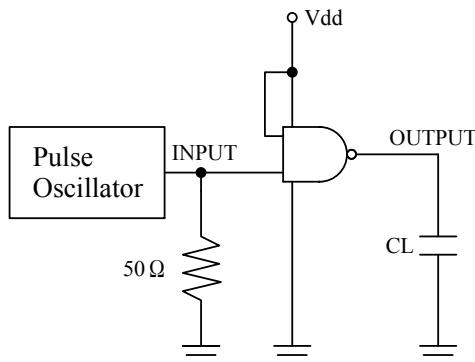
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■DC electrical characteristics

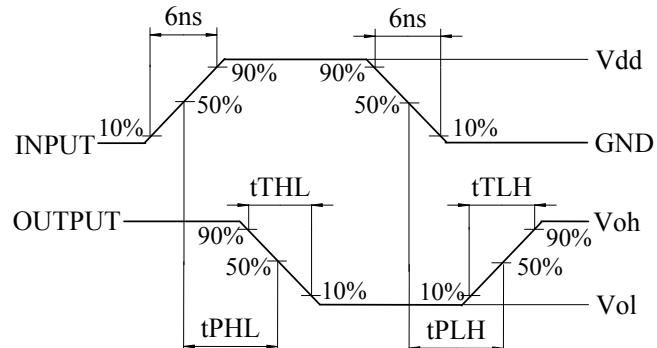
Parameter	Sym.	Vdd	Top=25°C			Top=-40 to +85°C		Unit	Condition	
			Min.	Typ.	Max.	Min.	Max.			
Input voltage	Vih	2.0	1.50			1.50		V		
		4.5	3.15			3.15				
		6.0	4.20			4.20				
	Vil	2.0			0.50		0.50	V		
		4.5			1.35		1.35			
		6.0			1.80		1.80			
Output voltage	Voh	2.0	1.90	2.00		1.90		V	Vin=Vih or Vil	Ioh=-20μA
		4.5	4.40	4.50		4.40				Ioh=-2mA
		6.0	5.90	6.00		5.90				Ioh=-2.6mA
		4.5	4.18	4.36		4.13			Vin=Vih	Iol=20μA
		6.0	5.68	5.84		5.63				Iol=2mA
	Vol	2.0		0.00	0.10		0.10	V	Vin=Vih	Iol=2.6mA
		4.5		0.00	0.10		0.10			Iol=20μA
		6.0		0.00	0.10		0.10		Vin=Vih	Iol=2mA
		4.5		0.11	0.26		0.33			Iol=2.6mA
		6.0		0.13	0.26		0.33			Iol=20μA
Input current	Iin	6.0	-0.1		0.1	-1.0	1.0	μA	Vin=Vdd or GND	
Static current	Idd	6.0			1.0		10.0	μA	Vin=Vdd or GND	

■Test circuit



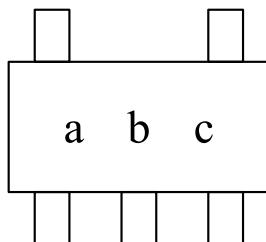
* Output should be opened when measuring current consumption.

■Measured wave pattern



■Marking

SOT-25



Sym.	Mark	Content
a	E	ELM7S series
b	1	ELM7S00B
c	A to Z (except I, O, X)	Lot No.